

Features

- $BV_{CEO} > -40V$
- Maximum Continuous Current $I_C = -1A$
- Low Saturation Voltage $V_{CE(sat)} < -500mV @ -1A$
- Complementary NPN Type: FCX491A
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.**
<https://www.diodes.com/quality/product-definitions/>
- **An automotive-compliant part is available under separate datasheet (FCX591AQ)**

Mechanical Data

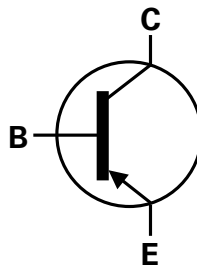
- Package: SOT89
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.05 grams (Approximate)

Application

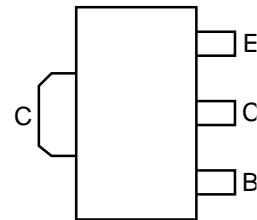
- Power MOSFET & IGBT gate driving
- Low loss power switching



Top View



Device Symbol



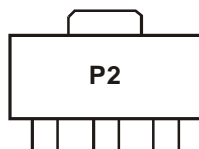
Top View
Pin Out

Ordering Information (Note 4)

Part Number	Status	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
						Qty.	Carrier
FCX591ATA	Released	SOT89	P2	7	12	1,000	Reel
FCX591A-13R	NRND (Use FCX591ATA)	SOT89	P2	13	12	4,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



P2 = Product Type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	V _{CB0}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	I _C	-1	A
Peak Pulse Current	I _{CM}	-2	A
Peak Base Current	I _B	-200	mA

Thermal Characteristics

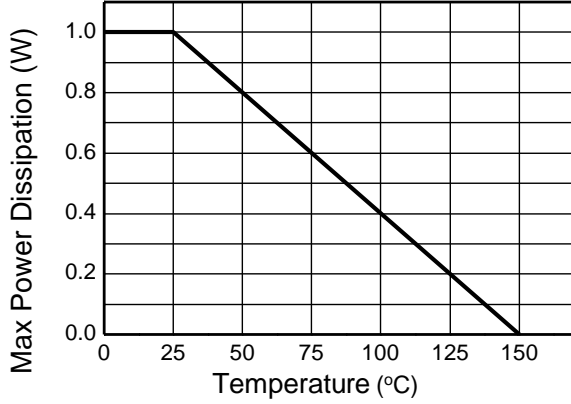
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	125	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R _{θJL}	10.01	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

ESD Ratings (Note 7)

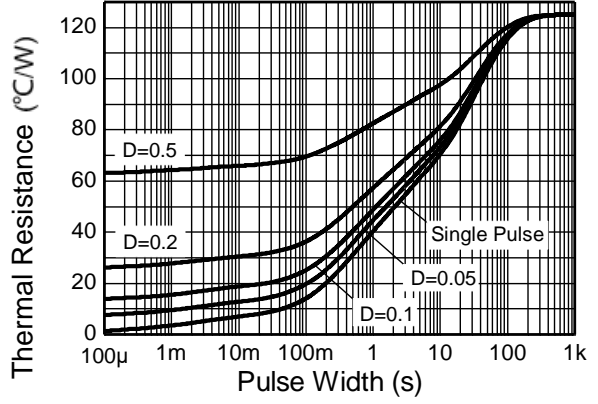
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; device measured when operating in steady state condition.
 6. Thermal resistance from junction to solder-point (on the exposed collector pad).
 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

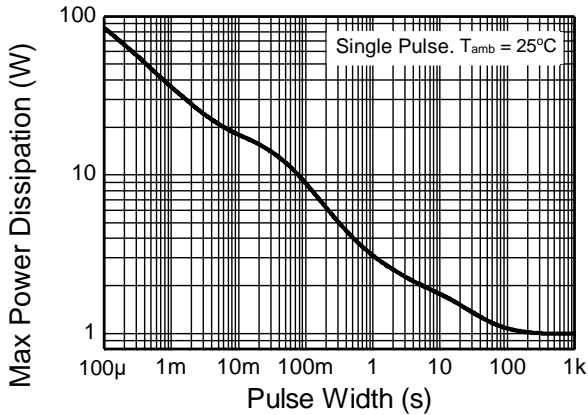
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



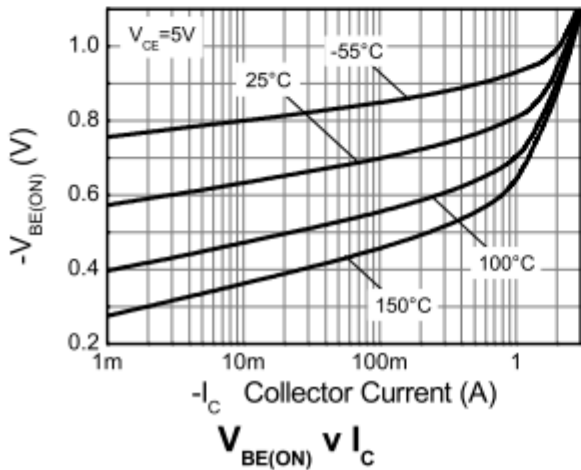
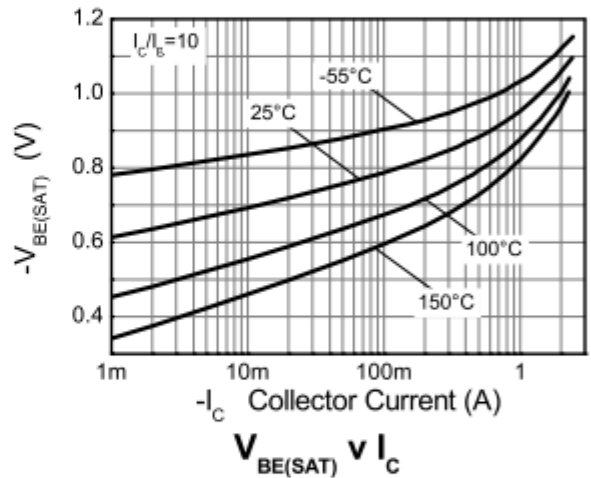
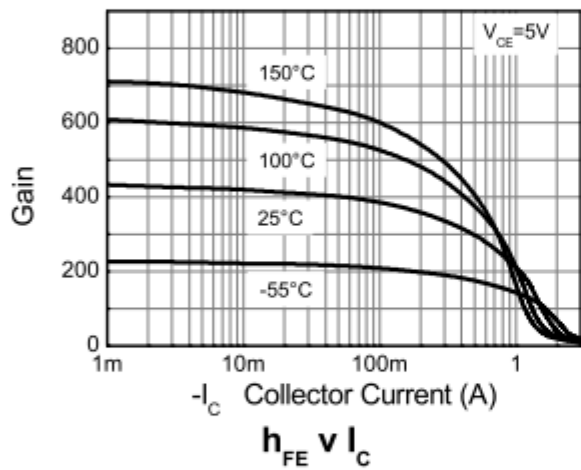
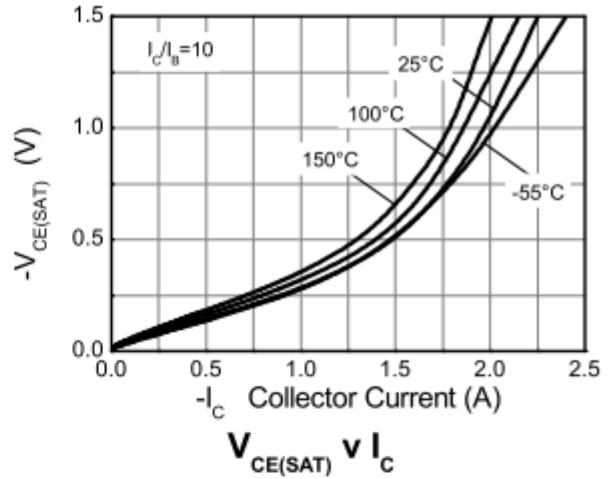
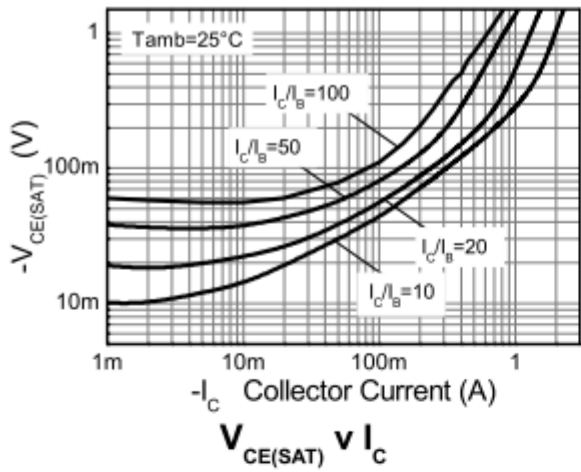
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-40	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	-40	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	—	—	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	—	—	-100	nA	V _{CB} = -30V
Emitter Cutoff Current	I _{EBO}	—	—	-100	nA	V _{EB} = -4V
Emitter Cutoff Current	I _{CES}	—	—	-100	nA	V _{CES} = -30V
DC Current Transfer Static Ratio (Note 8)	h _{FE}	300	—	—	—	I _C = -1mA, V _{CE} = -5V
		300	—	800		I _C = -100mA, V _{CE} = -5V
		250	—	—		I _C = -500mA, V _{CE} = -5V
		160	—	—		I _C = -1A, V _{CE} = -5V
		30	—	—		I _C = -2A, V _{CE} = -5V
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}	—	—	-0.2 -0.35 -0.5	V	I _C = -100mA, I _B = -1mA I _C = -500mA, I _B = -20mA I _C = -1A, I _B = -100mA
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}	—	—	-1.1	V	I _C = -1A, I _B = -50mA
Base-Emitter Turn-On Voltage (Note 8)	V _{BE(on)}	—	—	-1.0	V	I _C = -1A, V _{CE} = -5V
Transitional Frequency	f _T	150	—	—	MHz	I _E = -50mA, V _{CE} = -10V f = 100MHz
Output Capacitance	C _{obo}	—	—	10	pF	V _{CB} = -10V, f = 1MHz

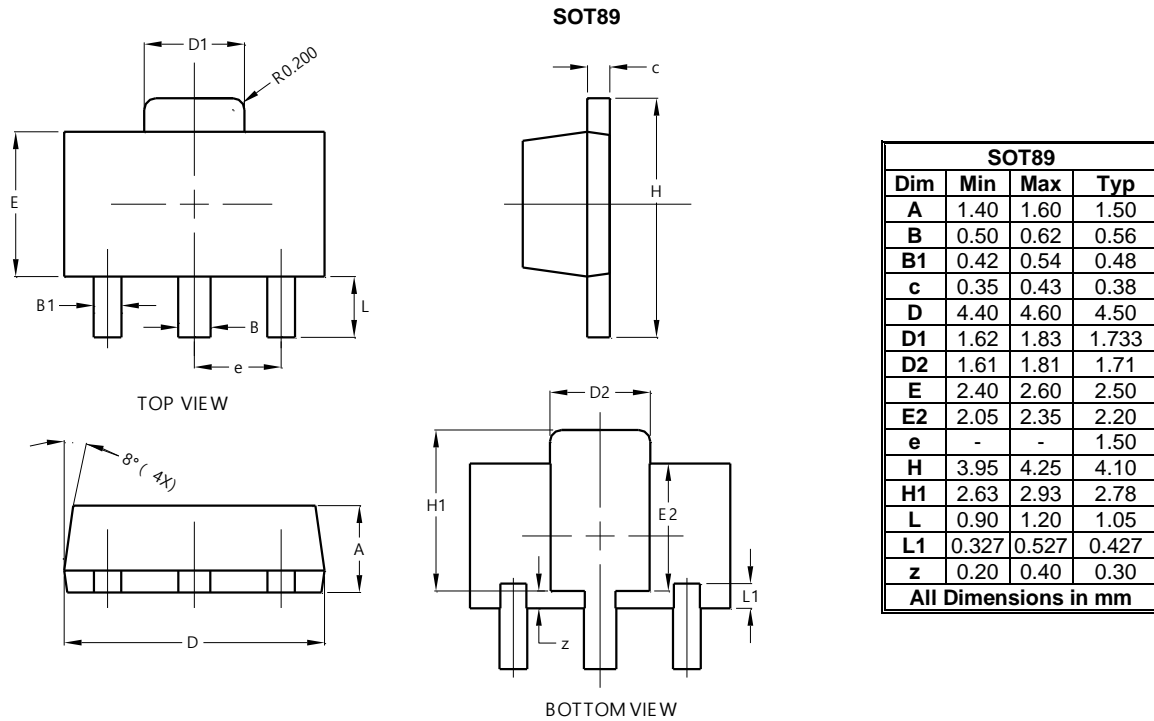
Note: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



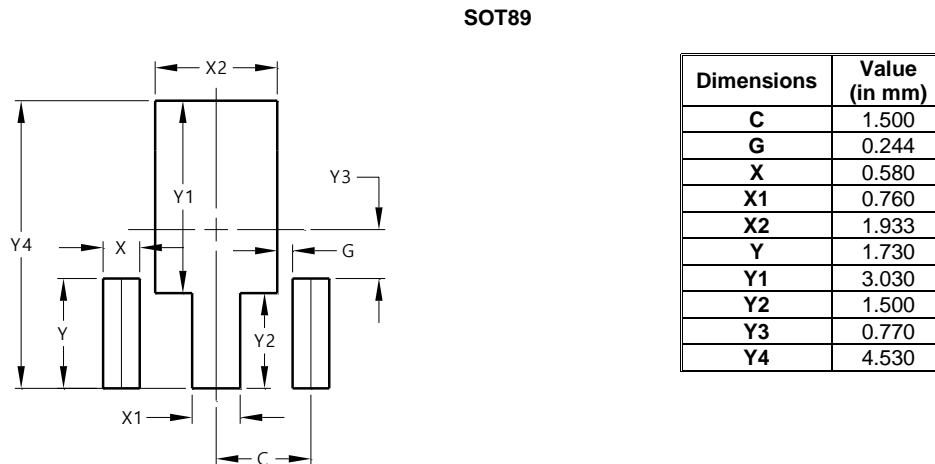
Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Suggested Pad Layout

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